

L Number	Hits	Search Text	DB	Time stamp
1	1	tortuous adj gate	USPAT; EPO; JPO; DERWENT	2003/09/30 14:42
2	0	20030080352.URPN.	USPAT	2003/09/30 14:42
3	30	MOSFET and asymmetric near3 (source near2 drain) with gate	USPAT; EPO; JPO; DERWENT	2003/09/30 14:44